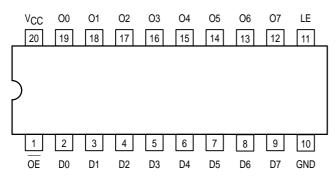
Low-Voltage CMOS Octal Transparent Latch Flow Through Pinout With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX573 is a high performance, non–inverting octal transparent latch operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V $_{\parallel}$ specification of 5.5V allows MC74LCX573 inputs to be safely driven from 5V devices.

The MC74LCX573 contains 8 D-type latches with 3-state standard outputs. When the Latch Enable (LE) input is HIGH, data on the Dn inputs enters the latches. In this condition, the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The 3-state standard outputs are controlled by the Output Enable (OE) input. When OE is LOW, the standard outputs are enabled. When OE is HIGH, the standard outputs are in the high impedance state, but this does not interfere with new data entering into the latches. The LCX573 flow through design facilitates easy PC board layout.

- Designed for 2.7 to 3.6V VCC Operation
- 5V Tolerant Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- IOFF Specification Guarantees High Impedance When VCC = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

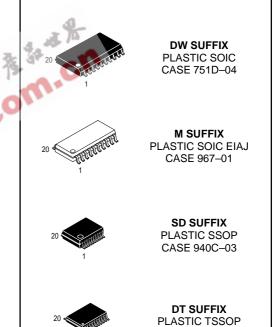
Pinout: 20-Lead (Top View)



MC74LCX573



LOW-VOLTAGE CMOS OCTAL TRANSPARENT LATCH



PIN NAMES

Pins	Function
OE LE D0-D7	Output Enable Input Latch Enable Input Data Inputs 3–State Latch Outputs
00-07	3–State Latch Outputs

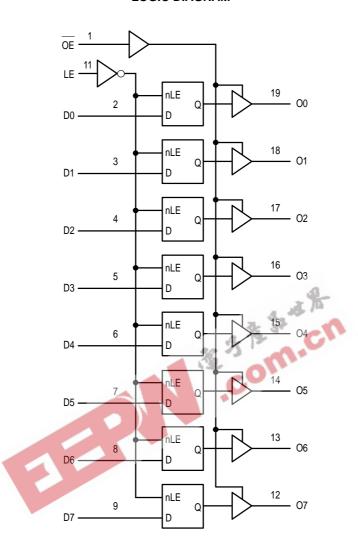


CASE 948E-02

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LOGIC DIAGRAM



	INPUTS		OUTPUTS	
OE	LE	Dn	On	OPERATING MODE
L L	H H	H L	H	Transparent (Latch Disabled); Read Latch
L L	L L	h I	H L	Latched (Latch Enabled) Read Latch
L	L	Х	NC	Hold; Read Latch
Н	L	Х	Z	Hold; Disabled Outputs
H H	H H	H	Z Z	Transparent (Latch Disabled); Disabled Outputs
H H	L L	h I	Z Z	Latched (Latch Enabled); Disabled Outputs

H = High Voltage Level; h = High Voltage Level One Setup Time Prior to the Latch Enable High-to-Low Transition; L = Low Voltage Level; I = Low Voltage Level One Setup Time Prior to the Latch Enable High-to-Low Transition; NC = No Change, State Prior to the Latch Enable High-to-Low Transition; X = High or Low Voltage Level or Transitions are Acceptable; Z = High Impedance State; For ICC Reasons DO NOT FLOAT Inputs

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
VCC	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 ≤ V _I ≤ +7.0		V
VO	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3–State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1.	V
lık	DC Input Diode Current	-50	V _I < GND	mA
loк	DC Output Diode Current	-50	V _O < GND	mA
		+50	VO > VCC	mA
lo	DC Output Source/Sink Current	±50		mA
Icc	DC Supply Current Per Supply Pin	±100		mA
IGND	DC Ground Current Per Ground Pin	±100		mA
TSTG	Storage Temperature Range	-65 to +150		°C

^{*} Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute—maximum—rated conditions is not implied.

1. Output in HIGH or LOW State. Io absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	20 75	Min	Тур	Max	Unit
Vcc	Supply Voltage	Operating ata Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage		0		5.5	V
Vo	Output Voltage (HIC	GH or LOW State) (3–State)	0 0		V _{CC} 5.5	V
IOH	HIGH Level Output Current, $V_{CC} = 3.0V - 3.0V$	6V			-24	mA
loL	LOW Level Output Current, V _{CC} = 3.0V - 3.0	6V			24	mA
ГОН	HIGH Level Output Current, V _{CC} = 2.7V - 3.	0V			-12	mA
l _{OL}	LOW Level Output Current, V _{CC} = 2.7V - 3.0	ΟV			12	mA
T _A	Operating Free-Air Temperature		-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, V _{IN} from 0 V _{CC} = 3.0V	.8V to 2.0V,	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		
Symbol	Characteristic	Condition	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage (Note 2.)	2.7V ≤ V _{CC} ≤ 3.6V	2.0		V
V _{IL}	LOW Level Input Voltage (Note 2.)	2.7V ≤ V _{CC} ≤ 3.6V		0.8	V
VOH	HIGH Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$; $I_{OH} = -100\mu A$	V _{CC} - 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -12mA$	2.2		
		$V_{CC} = 3.0V; I_{OH} = -18mA$	2.4		
		$V_{CC} = 3.0V; I_{OH} = -24mA$	2.2		
VOL	LOW Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$; $I_{OL} = 100\mu A$		0.2	V
		$V_{CC} = 2.7V; I_{OL} = 12mA$		0.4	
		V _{CC} = 3.0V; I _{OL} = 16mA		0.4	
		V _{CC} = 3.0V; I _{OL} = 24mA		0.55	

^{2.} These values of V_I are used to test DC electrical characteristics only.

DC ELECTRICAL CHARACTERISTICS (continued)

			T _A = -40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
Тį	Input Leakage Current	$2.7V \le V_{CC} \le 3.6V; \ 0V \le V_{I} \le 5.5V$		±5.0	μΑ
loz	3–State Output Current	$2.7 \le V_{CC} \le 3.6V$; $0V \le V_{O} \le 5.5V$; $V_{I} = V_{IH}$ or V_{IL}		±5.0	μΑ
lOFF	Power-Off Leakage Current	$V_{CC} = 0V$; V_I or $V_O = 5.5V$		10	μΑ
Icc	Quiescent Supply Current	$2.7 \le V_{CC} \le 3.6V$; $V_I = GND$ or V_{CC}		10	μΑ
		$2.7 \le V_{CC} \le 3.6V$; $3.6 \le V_I$ or $V_O \le 5.5V$		±10	μΑ
ΔlCC	Increase in ICC per Input	$2.7 \le V_{CC} \le 3.6V$; $V_{IH} = V_{CC} - 0.6V$		500	μΑ

AC CHARACTERISTICS ($t_R = t_F = 2.5 \text{ns}$; $C_L = 50 pF$; $R_L = 500 \Omega$)

				Lim	its		
				T _A = -40°C	c to +85°C		
			V _{CC} = 3.0	V to 3.6V	VCC =	= 2.7V	
Symbol	Parameter	Waveform	Min 🚜	Max	Min	Max	Unit
tPLH tPHL	Propagation Delay Dn to On	1	1.5 1.5	8.0 8.0	1.5 1.5	9.0 9.0	ns
^t PLH ^t PHL	Propagation Delay LE to On	3	1.5 1.5	8.5 8.5	1.5 1.5	9.5 9.5	ns
^t PZH ^t PZL	Output Enable Time to HIGH and LOW Level	2	1.5 1.5	8.5 8.5	1.5 1.5	9.5 9.5	ns
^t PHZ ^t PLZ	Output Disable Time from HIGH and LOW Level	2	1.5 1.5	6.5 6.5	1.5 1.5	7.0 7.0	ns
t _S	Setup Time, HIGH or LOW Dn to LE	3	2.5		2.5		ns
th	Hold Time, HIGH or LOW Dn to LE	3	1.5		1.5		ns
t _W	LE Pulse Width, HIGH	3	3.3		3.3		ns
toshl toslh	Output-to-Output Skew (Note 3.)			1.0 1.0			ns

^{3.} Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toshl) or LOW-to-HIGH (toslh); parameter guaranteed by design.

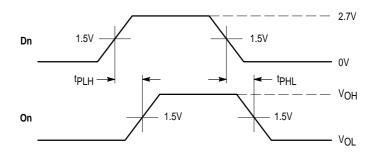
DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _{OLP}	Dynamic LOW Peak Voltage (Note 4.)	$V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$		0.8		V
V _{OLV}	Dynamic LOW Valley Voltage (Note 4.)	$V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$		0.8		V

^{4.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

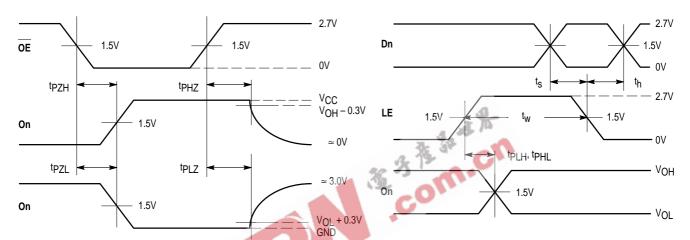
CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10MHz, $V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	25	pF



WAVEFORM 1 – PROPAGATION DELAYS

 t_R = t_F = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns



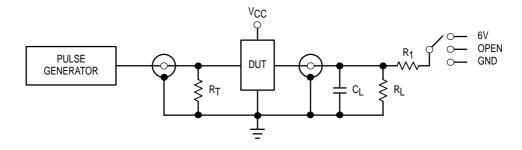
WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES

 $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1MHz; $t_W = 500$ ns

WAVEFORM 3 - LE to On PROPAGATION DELAYS, LE MINIMUM PULSE WIDTH, Dn to LE SETUP AND HOLD TIMES

 $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1MHz; $t_W = 500$ ns except when noted

Figure 1. AC Waveforms



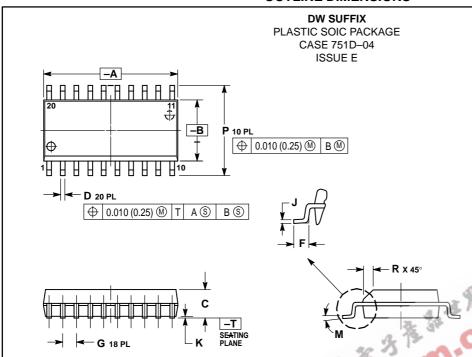
TEST	SWITCH
t _{PLH} , t _{PHL}	Open
tPZL, tPLZ	6V
Open Collector/Drain tpLH and tpHL	6V
tpzh, tphz	GND

 C_L = 50pF or equivalent (Includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 2. Test Circuit

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OUTLINE DIMENSIONS



NOTES:

- (OTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

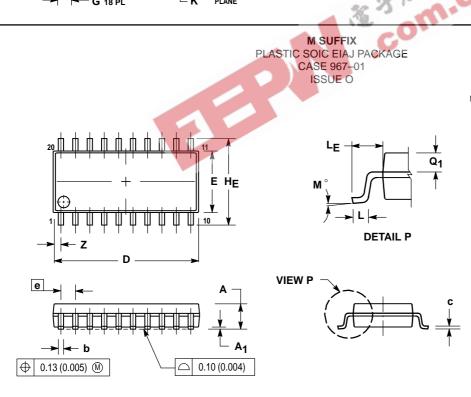
 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.150
- 4. MAXIMUM MOLD PROTRUSION 0.150
 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE
 DAMBAR PROTRUSION. ALLOWABLE
 DAMBAR PROTRUSION SHALL BE 0.13
 (0.005) TOTAL IN EXCESS OF D DIMENSION
 AT MAXIMUM MATERIAL CONDITION.

	MILLIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	12.65	12.95	0.499	0.510
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27	BSC	0.050	BSC
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009

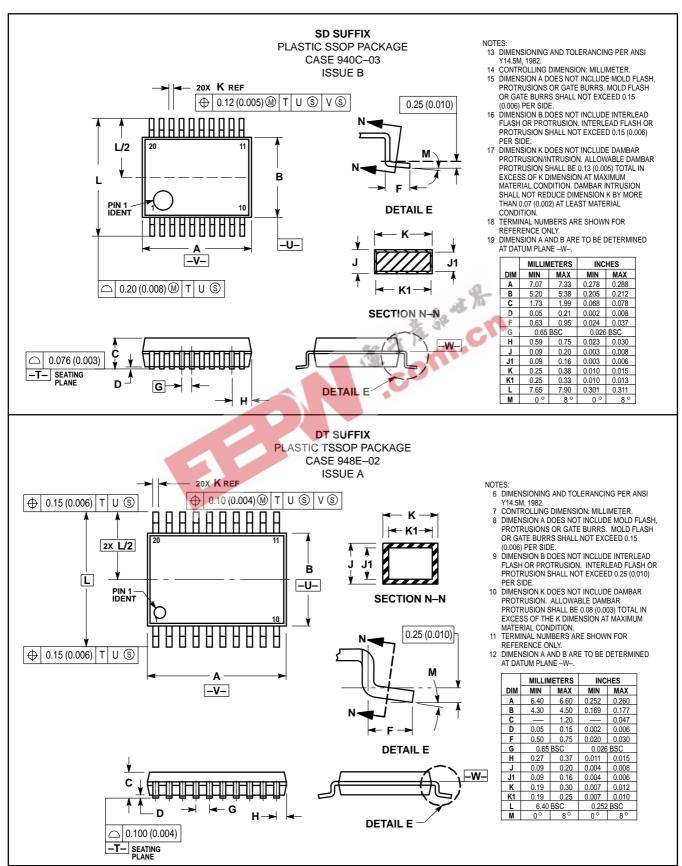
10.05 10.55 0.395 0.415 0.25 0.75 0.010 0.029



- 1 DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2 CONTROLLING DIMENSION: MILLIMETER.
 3 DIMENSIONS D AND E DO NOT INCLUDE MOLD
- FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 TERMINAL NUMBERS ARE SHOWN FOR
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
Α ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.18	0.27	0.007	0.011
D	12.35	12.80	0.486	0.504
E	5.10	5.45	0.201	0.215
е	1.27 BSC		0.050	BSC
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
ą	0.70	0.90	0.028	0.035
Z		0.81		0.032

OUTLINE DIMENSIONS



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MC74LCX573



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